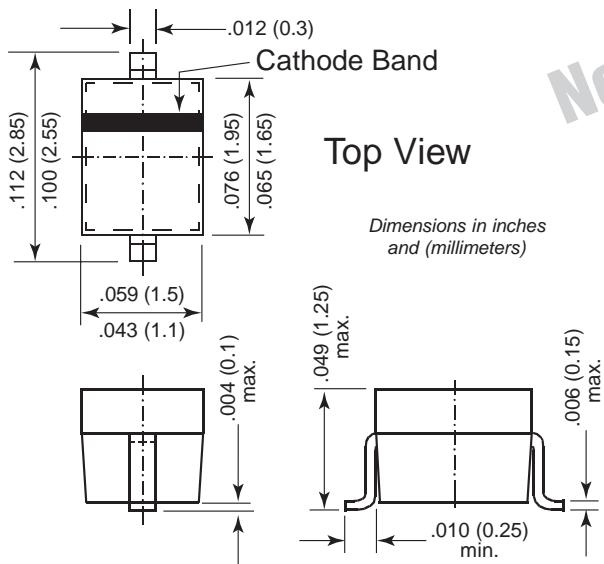
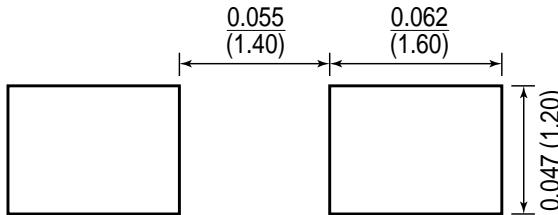



**SOD-323**

**Pad Layout SOD-323**


## Mechanical Data

**Case:** SOD-323 plastic package

**Weight:** approximately 0.004g

**Marking Code:** S2

**Packaging Codes/Options:**

D5/10K per 13" reel (8mm tape)  
D6/3K per 7" reel (8mm tape)

## Features

- Low turn-on voltage
- Fast switching
- Microminiature plastic package
- This device is protected by a PN junction guard ring against excessive voltage, such as electrostatic discharge.
- Ideal for protection of MOS devices, steering, biasing, and coupling diodes for fast switching and low logic level applications.

## Maximum Ratings and Thermal Characteristics ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Continuous Reverse Voltage	$V_R$	30	V
Forward Current	$I_F$	200	mA
Forward Surge Current, $t_p = 10 \text{ ms}$	$I_{FSM}$	1.0	A
Power Dissipation $T_C = 25^\circ\text{C}$	$P_{tot}$	250 <sup>(1)</sup>	mW
Thermal Resistance Junction to Ambient Air	$R_{\Theta JA}$	500 <sup>(1)</sup>	°C/W
Junction Temperature	$T_J$	150	°C
Storage Temperature Range	$T_S$	-65 to +150	°C

**Notes:** (1) Valid provided that electrodes are kept at ambient temperature

## Electrical Characteristics ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Breakdown Voltage	$BV_R$	$I_R = 100 \mu\text{A}$	30	—	—	V
Leakage Current	$I_R$	$V_R = 30 \text{ V}$	—	—	5.0	$\mu\text{A}$
Forward Voltage	$V_F$	$I_F = 2.0 \text{ mA}$	—	260	—	mV
		$I_F = 15 \text{ mA}$	—	320	—	
		$I_F = 100 \text{ mA}$	—	420	—	
		$I_F = 200 \text{ mA}$	—	490	550	
Junction Capacitance	$C_{tot}$	$V_R = 10 \text{ V}, f = 1.0 \text{ MHz}$	—	—	15	pF